NSN 5961-00-925-6518

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-925-6518 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 25.0 collector to base voltage/static/emitter open all transistor and 20.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset all transistor **Capacitance Rating In Picofarads:** 8.0 all transistor **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead **Specification Data:** 80131-release4218 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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